

JAN 08 2007

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. .... 10/072,415  
Filing Date ..... February 5, 2002  
Inventor ..... Ji Ung Lee et al.  
Assignee ..... Micron Technology, Inc.  
Group Art Unit ..... 2891  
Examiner ..... Steven J. Fulk  
Confirmation No. .... 5182  
Customer No. .... 021567  
Attorney's Docket No. .... MI30-068  
Title: Field Effect Transistor Fabrication Methods, Field Emission Device Fabrication  
Methods, and Field Emission Device Operational Methods

RESPONSE TO AUGUST 8, 2006 OFFICE ACTION

To: Mail Stop Amendment  
Assistant Commissioner for Patents  
P.O. Box 1450  
Alexandria VA 22313-1450

From: James D. Shaurette (Tel. 509-624-4276; Fax 509-838-3424)  
Wells, St. John, P.S.  
601 W. First Avenue, Suite 1300  
Spokane, WA 99201-3828

Sir:

Responsive to the Office Action dated August 8, 2006, Applicants amend and  
remark as follows:

AMENDMENTS

01/11/2007 EFLORES 00000001 230925 10072415

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